

**REMARKS**

**Election/Restriction**

The Examiner has made a restriction requirement in accordance with 35 U.S.C. §121 between:

Species I: Claims 1 – 14 and 21, drawn to a method for fabrication of an etched groove GaN-based permeable-base transistor device, classified in class 438, subclass 93.

Species II: Claims 15 – 20, drawn to an etched grooved GaN-based permeable-based transistor device classified in class 257, subclass 197.

In response to the Examiner's restriction requirement, election is hereby made **WITHOUT TRAVERSE** to prosecute the invention of **Species I, claims 1- 14 and 21**. Claims 15 – 20 have been withdrawn without prejudice with certain amendments noted therein.

Applicant believes the above amendments and remarks to be fully responsive to the Office Action, thereby placing this application in condition for allowance. No new matter is added. Applicant requests speedy reconsideration, and further requests that Examiner contact its attorney by telephone, facsimile, or email for quickest resolution, if there are any remaining issues.

Respectfully submitted,

**/Scott J. Asmus, Reg. No. 42,269/**

Cus. No. 42716  
Maine & Asmus  
PO Box 3445  
Nashua, NH 03061-3445  
Tel. No. (603) 886-6100  
Fax. No. (603) 886-4796  
patents@maineandasmus.com

Scott J. Asmus, Reg. No. 42,269  
Andrew P. Cernota, Reg. No. 52,711  
Kristina M. Grasso, Reg. No. 39,205  
Attorneys/Agents for Applicant